

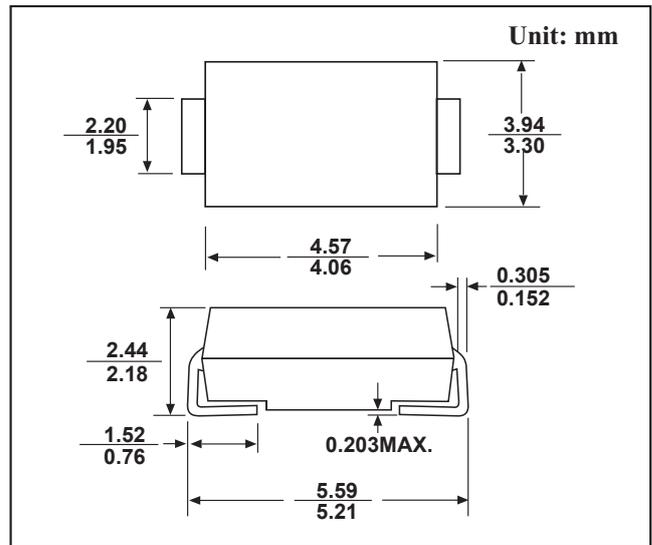
SMB SCHOTTKY BARRIER DIODE

FEATURES

- The plastic package carries Underwrites Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- High reliability
- High temperature soldering guaranteed:260 °C/10 seconds at terminals
- Component in accordance to RoHs 2015/863 and WEEE 2012/19/EU

MECHANICAL DATA

- Case style: SMB molded plastic
- Mounting position: Any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

TYPE NUMBER	SYMBOL	SS22	SS23	SS24	SS25	SS26	SS28	SS210	SS215	SS220	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	20	30	40	50	60	80	100	150	200	V
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	57	71	105	140	V
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	80	100	150	200	V
Maximum Average Forward rectified Current 0.375"(9.5mm) lead length	$I_{F(AV)}$	2.0									A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	I_{FSM}	30.0									A
Maximum instantaneous forward voltage at 2.0 A	V_F	0.55		0.75		0.85		0.90		0.95	V
Maximum reverse current at rated DC blocking voltage per diode	@ $T_A=25^\circ C$	0.2									mA
	@ $T_A=100^\circ C$	10.0									
Typical Thermal Resistance	$R_{\theta JA}$	55.0									°C/W
Typical junction capacitance	C_j	75									pF
Storage Temperature	T_{STG}	- 55 ----- + 150									°C
Operation Junction Temperature	T_j	- 55 ----- + 125									°C

RATINGS AND CHARACTERISTIC CURVES

FIG. 1- FORWARD CURRENT DERATING CURVE

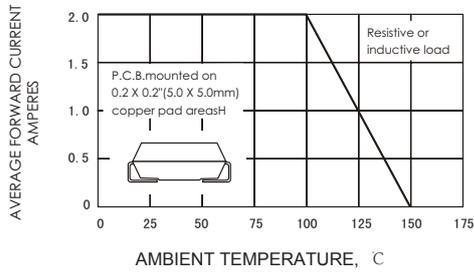


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

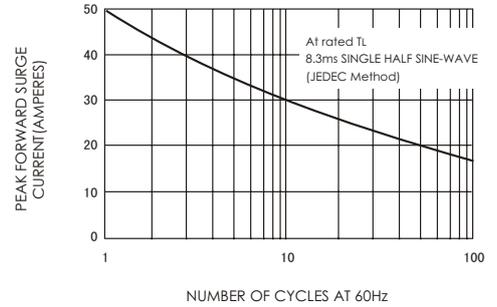


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

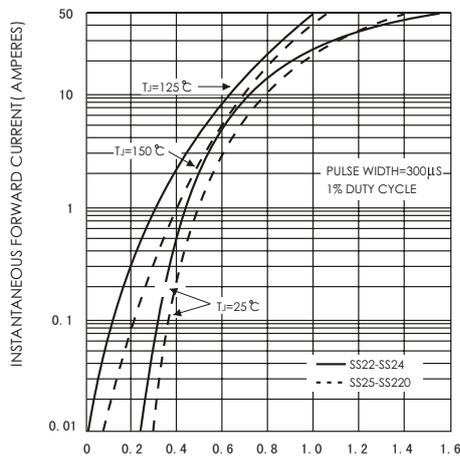


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

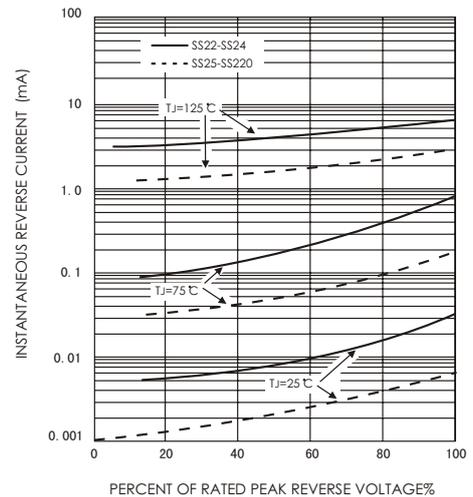


FIG. 5-TYPICAL JUNCTION CAPACITANCE

